EXPERIMENTALLY DERIVED RESISTIVITY FOR DIELECTRIC SAMPLES FROM THE CRRES INTERNAL DISCHARGE MONITOR

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Abstract

Resistivity values were experimentally determined using charge storage methods for six samples remaining from the construction of the Internal Discharge Monitor (IDM) flown on the Combined Release and Radiation Effects Satellite (CRRES). Three tests were performed over a period of four to five weeks each in a vacuum of $\sim 5\times10^{-6}$ torr with an average temperature of ~25 °C to simulate a space environment. Samples tested included FR4, PTFE, and alumina with copper electrodes attached to one or more of the sample surfaces. Micaply FR4 circuit board material was found to have a resistivity of $\sim 3\times10^{18}$ ohm-cm. Fiber filled PTFE exhibited little polarization current and a resistivity of $\sim 3\times10^{20}$ ohm-cm. Alumina bled away charge at a rapid rate making resistivity calculation difficult; the best estimate of resistivity is $\sim 10^{17}$ ohm-cm. Experimentally determined resistivity values were two to three orders of magnitude more than found using standard ASTM test methods. The one minute wait time suggested for the standard ASTM tests is much shorter than the measured polarization current decay times for each sample indicating that the primary currents used to determine ASTM resistivity are caused by the polarization of molecules in the applied electric field rather than charge transport through the bulk of the dielectric. Testing over much longer periods of time in vacuum is required to allow this polarization current to decay away and to allow the observation of charged particles transport through a dielectric material. Application of a simple physics-based model allows separation of the polarization current and dark current components from long duration measurements of resistivity over day- to month-long time scales. Model parameters are directly related to the magnitude of charge transfer and storage and the rate of charge transport.

Introduction

Standard constant-voltage ASTM test methods of very high resistivity dielectrics [1,2] do not provide accurate resistivity values for dielectrics appropriate for use in spacecraft charging applications [3,4]. These standard methods rely on electrometer measurements of current, voltage or resistance and are typically instrumentation resolution limited to accurate measurements of resistivities of less than 10^{12} to 10^{17} $\Omega\cdot$cm [1,4]. Inconsistencies in sample humidity, sample temperature, initial voltages and other factors from such tests cause significant variability in results [1]. Further, the duration of standard tests are short enough that the primary currents used to determine resistivity are often caused by the polarization of molecules by the applied electric field rather than by charge transport through the bulk of the dielectric [4,5,6]. Testing over much longer periods of time in a well-controlled vacuum environment is required to allow this polarization current to become small so that accurate observation of the more relevant charged particle transport through a dielectric material is possible. For space applications this is particularly important since dielectrics on the spacecraft will be exposed to space plasmas and radiation for months or years. Unless dissipated by leakage through the dielectric, charge will build up within the dielectric inducing large electric fields that can lead to dielectric breakdown and potentially harmful ESD pulses.

Selected samples remaining from the Internal Discharge Monitor (IDM) experiment on the CRRES satellite [7,8] were tested for charge storage for NASA at the Jet Propulsion Laboratory. The sample set on CRRES was chosen to cover a range of dark current resistivity values and polarization magnitudes and rates. Hence, the set provides an excellent test bed for both the charge storage method of resistivity measurements and behavior of dielectrics in the space environment. By measuring the decay of stored charge in these dielectric samples, more accurate and appropriate resistivity values for the sample materials have been determined. Preliminary measurements of resistivities measured with the charge storage method for similar samples were shown to be critical in accurate modeling of the discharge pulsing of samples during the CRRES mission [9,10]. The new resistivity values reported here are expected to further

enhance the usefulness of the knowledge gained from the IDM experiment by producing experimental resistivity values for several of the samples.

Samples tested were 5x5 cm squares with copper electrodes on one or more surfaces. Materials included PTFE fiberglass, Micaply FR4, and Alumina (Al_2O_3) [7] Three tests were performed over a period of four to five weeks each in a vacuum of ~5×10^{-6} torr to simulate a space environment. Details for each sample, including standard ASTM material properties and the corresponding CRRES IDM channel, are given in Table 1. Pulse histories for each sample are documented in the references [11,12,13].

Table 1. List of Samples with CRRES IDM channel reference

Material	Thickness (cm)	Electrode	Mount Type	IDM Channel	Material Properties (ASTM) [14] ϵ_r	ρ_{ASTM} ($\Omega\cdot$cm)	δ_{1MHz}	E_S (MV/m)
PTFE	0.229	Dual	Open	11	2.0	1×10^{18}	0.0001	130
PTFE	0.229	Back	Open	16				
FR4	0.119	Back	Closed	15	5.7	2.1×10^{17}	0.035	16.5
FR4	0.119	Back	Open	15				
FR4	0.317	Dual	Open	8				
FR4	0.317	Back	Open	4,12				
Alumina	0.102	Back	Open	7	9.6	1×10^{14}	0.001	16.5

Test Procedure

Samples were mounted on a circular carousel (Figure 1) inserted into a vacuum chamber behind another metallic plate with a single opening into the interior allowing each sample to be charged individually. Also mounted on the shutter was an electrically isolated sensor plate used to measure each sample's surface potential one at a time from outside of the chamber with a Trek electrostatic voltmeter, model 341 (Figure 2). Measurements represented an average surface potential over an area approximately equal to the 19 cm^2 surface area of the sensor plate. Connections to the electrodes on the back of each sample were brought through the chamber door for individual control or monitoring of each sample when charging. A calibration coefficient was calculated for each sample to relate measured potentials to actual sample surface potentials.

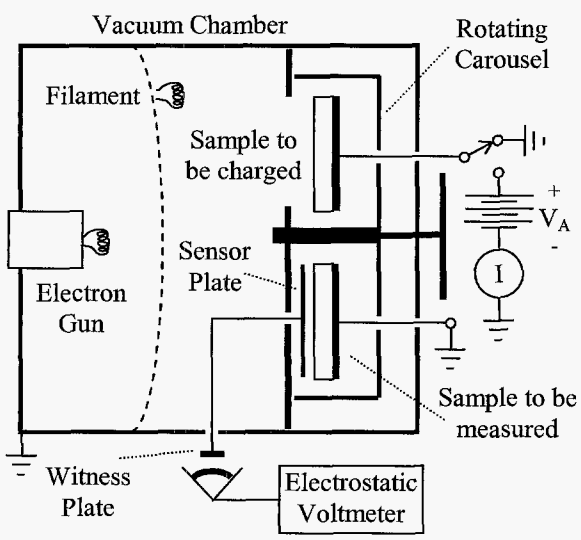


Figure 1. A diagram of the vacuum chamber arrangement as used while testing the CRRES IDM samples.

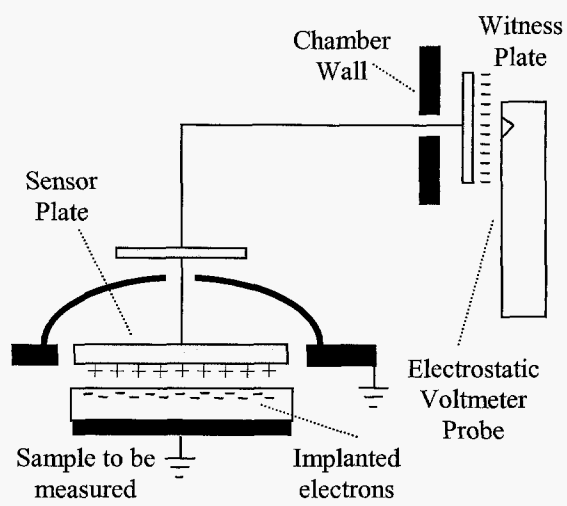


Figure 2. Detail of the capacitive measurement system used to measure sample surface potential

Samples were charged with electrons by one of two methods: placing a positive potential on each sample and attracting thermionically generated electrons from an energized filament near ground potential, or by floating an energized filament at a highly negative potential compared to the grounded samples. In either case, the energy of incident electrons was roughly equal to the difference between the filament and the sample potentials.

Three charging runs lasting from 20, 25, and 35 days respectively were performed with the CRRES IDM samples. Two charging runs were conducted successively while the third run was performed on the same samples after approximately two months at atmosphere. Sample temperature was not closely monitored, but an average temperature of 25 °C (laboratory room temperature) is assumed. Measurements of the surface potentials were taken initially every few minutes, but at the changes between successive measurements became smaller, the interval between measurements increased first to hours then to days.

Further details of the instrumentation and test methods are found in the references [3,15].

Resistivity Model

Since the actual amount of charged particles on the surface of the materials could not be measured directly, each sample's surface potential was monitored to observe the changes in the electric field due to polarization of the material and, ultimately, dark current conduction of charge though the dielectric. A relatively rapid initial drop in the surface potential was expected for each sample due to dielectric polarization in the sample material. This initial decrease in potential was found to vary widely due to material properties. As any polar molecules in the material rotated to align with the electric field created by the charges on the surface of the sample, or migrate within the dielectric to interfaces, they created a polarization electric field in opposition to that formed by the incident electrons. Since the measured surface potential was dependent on electric field strength from the sample, the opposing field reduced the measured voltage without necessarily indicating a reduction in the number of charged particles on the surface of the sample. Simultaneously, charged particles may have been conducted through the material, but the majority of the short-term change in surface potential for high resistivity materials was thought to be through polarization of the sample material. As polarization reached saturation, further change in surface potential due to this effect became negligible and any further change was due to a reduction in the number of charged particles remaining on the surface of the charged sample. The charged particles that left the surface moved into the dielectric material filling electron traps or conducting through the material to ground. The dark current resistivity of the material was determined by the rate of charged particle transport, in the long-term asymptotic limit of charge storage measurements.

A simple model of the measured surface voltage as a function of elapsed time for the charge storage method $V_{CS}(t)$ in terms of the initial and final surface voltages (V_o *and* V_∞) and initial and final relative permittivities (ϵ_r^o and ϵ_r^∞, where ϵ_o=8.854·10^{-12} F/m is the permittivity of free space, ϵ is the permittivity in a dielectric medium, and $\epsilon_r \equiv \epsilon/\epsilon_o$ is the relative permittivity) predicts [E]

$$V_{CS}(t;V_o,V_\infty,\varepsilon_r^o,\varepsilon_r^\infty,\tau_{DC},\tau_P)=\frac{\left[(V_o-V_\infty)e^{-t/\tau_{DC}}+V_\infty\right]}{\left(\varepsilon_r^o-\varepsilon_r^\infty\right)e^{-t/\tau_P}+\varepsilon_r^\infty} \qquad \textbf{(1)}$$

The polarization decay time, τ_P, measures the rate of the response of the medium to an applied electric field, and can be thought of as the rate at which the dipoles in the material align within the material to the electric field E. It is the time it takes for the bound surface charge to increase to (1-^{1}/e) (or 63%) of its final value. The charge storage decay time, τ_{DC}, is the time it takes for the free surface charge to drop to 1/e (or 37%) of its initial value and is directly proportional to the dark current resistivity $\rho_{DC}=\tau_{DC}/(\epsilon_o\,\epsilon_r^\infty)$. Note that in this simple model, the polarization decay time, dark current decay time and resistivity are all intrinsic material properties, independent of surface area or thickness. If there is no initial polarization, ϵ_r^o=1. If there are no free charges trapped within the dielectric as it is transported through the material and t→ ∞, then this results in a residual potential, V_∞=0. In the limit of short time, with $\tau_{DC} \gg \tau_P$ and ϵ_r^o=1 and,

$$V_{CS}^o(t;V_o,\varepsilon_r^\infty,\tau_P)\rightarrow V_o\left[\varepsilon_r^\infty\left(1-e^{-t/\tau_P}\right)\right]^{-1} \qquad \textbf{(2)}$$

In the limit of long time, with $\tau_{DC} \gg \tau_P$, ϵ_r^o=1 and V_∞=0,

$$V_{CS}^\infty(t;V_o,\tau_{DC})\rightarrow V_o\,e^{-t/\tau_{DC}} \qquad \textbf{(3)}$$

Test Results

A total of seven samples were charged and monitored for each of the three runs. Analyses of the data for three of the samples are presented below representing the general results for each sample material. For each analysis presented, the surface voltage measurements were fit using a least-squares fit method for:

(i) the full data set using Eq. (1) with five fitting parameters, V_∞, ϵ_r^o, ϵ_r^∞, τ_{DC}, and τ_P,
(ii) the full data set using Eq. (1) with three fitting parameters ϵ_r^∞, τ_{DC}, and τ_P, plus ϵ_r^o=1 and V_∞=0,
(iii) the initial six data points using Eq. (2) with ϵ_r^∞ and τ_P as fitting parameters, and
(iv) the last six data points using Eq. (3) with τ_{DC} as a fitting parameter.

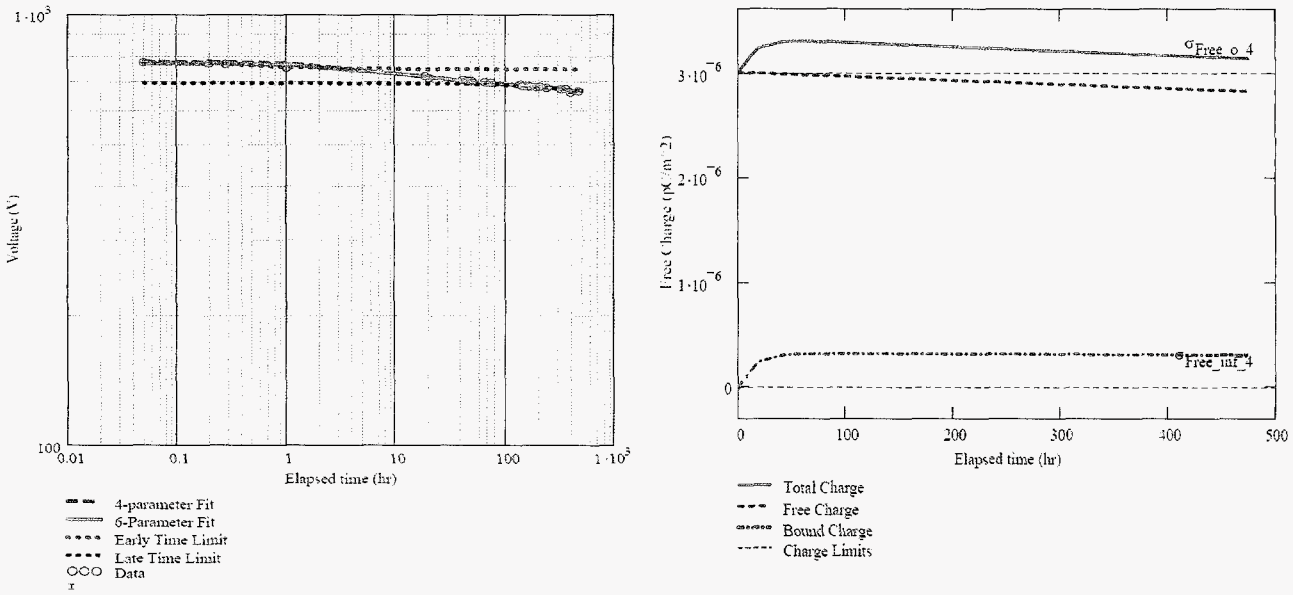
In each case, V_o was set to the measured initial voltage. Results for the fits are listed in Table 2.

Table 2. Experimentally Determined Resistivity values for CRRES IDM samples

Material	Thickness (cm)	ϵ_r^∞	τ_P (day)	τ_{DC} (day)	$\rho_{3\ parameter}$ (ohm-cm)	$\rho_{5\ paramter}$ (ohm-cm)
PTFE	0.229	1.12	0.72	436	2.9×10^{20}	3.0×10^{20}
FR4	0.317	1.23	0.59	26.9	2.6×10^{18}	4.1×10^{18}
Alumina	0.102	8.98	0.63	14.5	3.5×10^{17}	1.3×10^{17}

PTFE Charge Decay

The decay pattern of the PTFE samples is significantly different from that of the other samples tested, and reflects the physical properties of the material. PTFE is known as a non-polar polymer, with a very low polarizability evidenced by its low dielectric constant of 2.1 [14, p. 120]. The ratio of total charge to free charge in Figure 3b is indicative of this relatively small amount of polarization in PTFE. Because of the symmetry of the C_2F_4 PTFE mer and the high affinity of fluorine for its electrons, the polymer has no permanent dipole moment and orientational polarization is not a major contributor [14, p. 10]. Thus, polarization in PTFE results rapidly from induced dipoles through electronic and atomic polarization or more slowly due to defects through interfacial polarizability. Response of the long chain polymers and modifications of defects occurs slowly for PTFE, as evidenced by the relatively long polarization decay time τ_P~*18 hr* and the slow rise of the bound charge predicted in Figure 3b. PTFE has a very high dark current resistivity; this is evident in the very large value of the dark current decay constant τ_{DC}~*1 yr* and in the slow decay of free charge predicted in Figure 3b.



a. Surface potential as a function of time

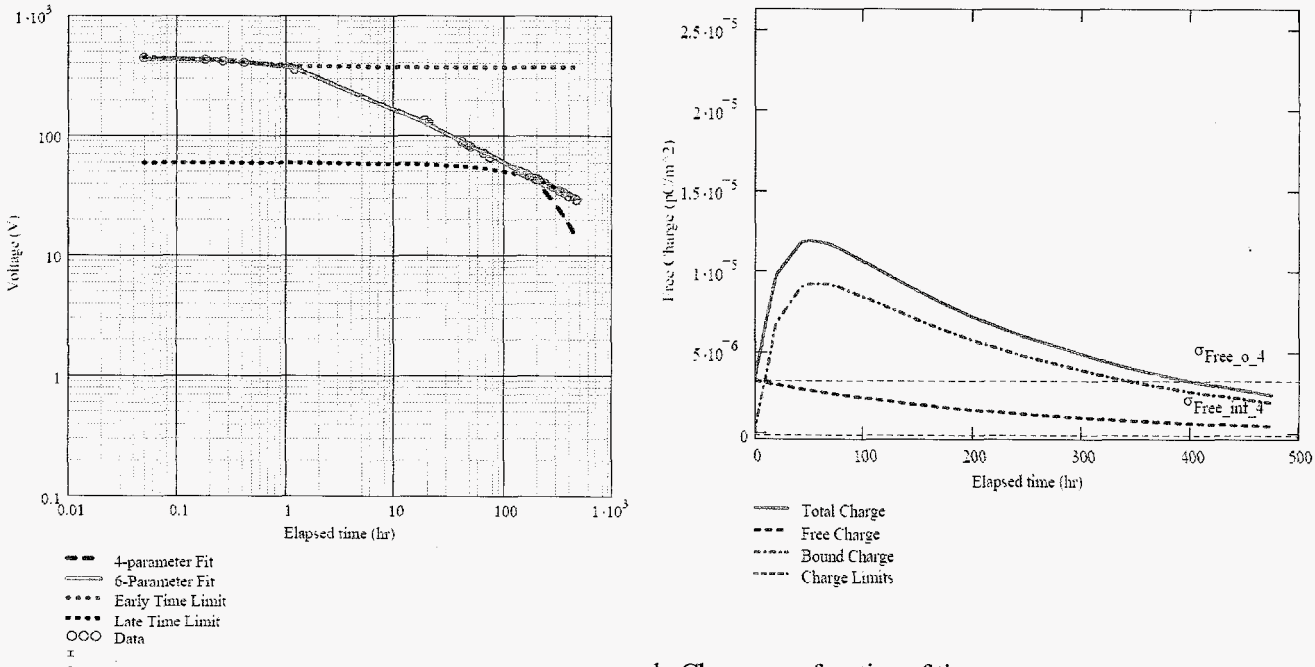
b. Charge as a function of elapsed time

Figure 3. Surface Potentials and charge as functions of time for PTFE. Charge functions are based on the 5 parameter fits.

FR4 Charge Decay

The FR4 samples displayed intermediate charge storage characteristics. FR4 showed a fairly rapid initial drop in potential immediately after charging due to polarization. Response of the long chain polymers and modifications of defects were similar to those for PTFE, as evidenced by a similar long polarization decay time τ_P~*18 hr* and the slow

rise of the bound charge predicted in Figure 4b. The higher ratio of total charge to free charge in Figure 4b is indicative of higher polarization than in PTFE and a relative dielectric constant of >5. The polymer in FR4 has a permanent dipole and the defect density is higher due to the composite nature of the material. The FR4 has a dark current resistivity between the other two samples; this is evident in the intermediate dark current decay constant τ_{DC}~*4 days* and in the modest decay of free charge predicted in Figure 4b.



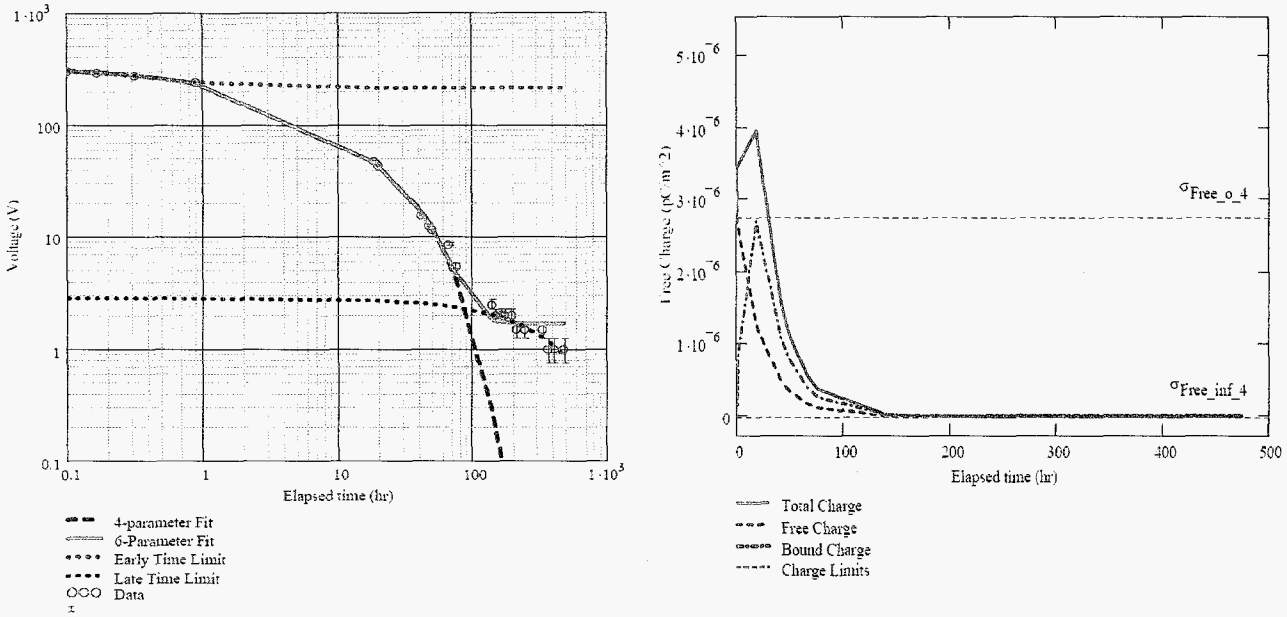
a. Surface Potential as a function of time

b. Charge as a function of time

Figure 4. Surface Potentials and charge as functions of time for FR4. Charge functions are based on the 5 parameter fits.

Alumina Charge Decay

The behavior of the alumina sample is significantly different than the PTFE and FR4 polymer samples, due to the structure of the ceramic. The alumina has a much lower dark current resistivity than either polymer; this is evident in the relatively small dark current decay constant τ_{DC}~*20 hr* and in the more rapid decay of free charge predicted in Figure 4b. It is interesting to note that there is a small charge (~1% of the initial free charge) that decays with a very long decay constant of >1 yr. This is evident in the long time charge decay in Figure 5a. We speculate that this may be related to the slow dissipation of charge trapped in deep level defect states of the alumina. The alumina has one of the highest dielectric constants of common ceramics of about 10. This follows mostly from the large permanent dipole moment of the Al_2O_3 unit cell that results from appreciable charge redistribution in the ionic/covalent bonds. This leads to a large initial rise in the bound charge (see Figure 5b). However, the bound charge never exceeds the initial free charge because the polarization decay constant τ_P~*6 hr* is not too much shorter than τ_{DC}. The observation that the polarization decay constant of alumina is shorter than the polymers is too be expected as much of the polarization of alumina results from atomic polarizability, that is distortion of the atoms within the unit cell. This behavior is evident in the decay of the bound charge in Figure 5b.



a. Surface Potential as a function of time

b. Charge as a function of time

Figure 5. Surface Potentials and charge as functions of time for Alumina. Charge functions are based on the 5 parameter fits.

Conclusion

Laboratory testing has shown that resistivity values for samples tested are generally two to three orders of magnitude more than those given by standard ASTM test methods. The difference in measured resistivity is the dominance of polarization currents in the first hours after the application of an external electric field. When charge is deposited on the surface of dielectric samples held in a vacuum, the polarization current decays to an insignificant value. Without the presence of the polarization current, charge transport can more easily be observed and the resistivity calculated.

Three dielectric materials were tested and general results are listed in the analysis above. Micaply FR4 circuit board material was found to have a resistivity of $\sim 3\times10^{19}$ ohm-cm. Fiber filled PTFE exhibited little polarization current and a resistivity of $\sim 3\times10^{20}$ ohm-cm. The last material tested, Alumina, bled away charge at a rapid rate making resistivity calculation difficult. The best guess value for the resistivity of Alumina is $\sim 10^{17}$ ohm-cm though this value is not definite. These results need to be verified through further analysis of the gathered data including that for other thicknesses and additional electrode configurations.

With these measured values, and others to come, the work begun by Frederickson and Brautigam [13] can be continued for more CRRES samples. It should be noted that the values calculated here are for samples that have not been exposed to radiation and have only been exposed to small amounts of low energy electrons. The resistivity of these materials may change, and change significantly, with exposure to space radiation.

Acknowledgements

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